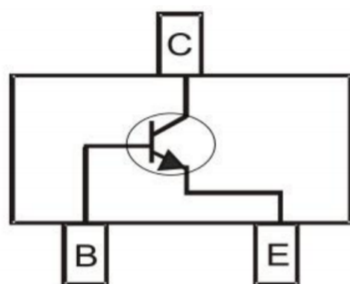


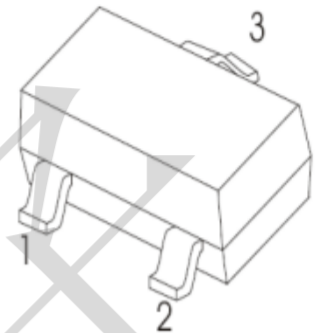
FEATURES

- Complementary to MMBT2907AW
- Small Package
for switching and amplifier applications



SOT323

1. BASE
2. EMITTER
3. COLLECTOR



AbsoluteMaximumRatings($T_a=25^{\circ}\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	75	V
Collector Emitter Voltage	V_{CEO}	40	V
Emitter Base Voltage	V_{EBO}	6	V
Collector Current	I_C	600	mA
Power Dissipation	P_{tot}	150	mW
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^{\circ}\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $V_{CE} = 10\text{ V}$, $I_C = 0.1\text{ mA}$ at $V_{CE} = 10\text{ V}$, $I_C = 1\text{ mA}$ at $V_{CE} = 10\text{ V}$, $I_C = 10\text{ mA}$ at $V_{CE} = 1\text{ V}$, $I_C = 150\text{ mA}$ at $V_{CE} = 10\text{ V}$, $I_C = 150\text{ mA}$ at $V_{CE} = 10\text{ V}$, $I_C = 500\text{ mA}$	h_{FE} h_{FE} h_{FE} h_{FE} h_{FE} h_{FE}	35 50 75 50 100 40	- - - - 300 -	- - - - - -
Collector Base Cutoff Current at $V_{CB} = 50\text{ V}$ at $V_{CB} = 60\text{ V}$	I_{CBO}	-	100	nA
Emitter Base Cutoff Current at $V_{EB} = 3\text{ V}$	I_{EBO}	-	100	nA
Collector Base Breakdown Voltage at $I_C = 10\text{ }\mu\text{A}$	$V_{(BR)CBO}$	75	-	V
Collector Emitter Breakdown Voltage at $I_C = 10\text{ mA}$	$V_{(BR)CEO}$	40	-	V
Emitter Base Breakdown Voltage at $I_E = 10\text{ }\mu\text{A}$	$V_{(BR)EBO}$	6	-	V
Collector Emitter Saturation Voltage at $I_C = 150\text{ mA}$, $I_B = 15\text{ mA}$ at $I_C = 500\text{ mA}$, $I_B = 50\text{ mA}$	$V_{CE(sat)}$	- -	0.3 1	V
Base Emitter Saturation Voltage at $I_C = 150\text{ mA}$, $I_B = 15\text{ mA}$ at $I_C = 500\text{ mA}$, $I_B = 50\text{ mA}$	$V_{BE(sat)}$	0.6 -	1.2 2	V
Transition Frequency at $V_{CE} = 20\text{ V}$, $-I_E = 20\text{ mA}$, $f = 100\text{ MHz}$	f_T	300	-	MHz
Collector Output Capacitance at $V_{CB} = 10\text{ V}$, $f = 100\text{ KHz}$	C_{ob}	-	8	pF
Delay Time at $V_{CC} = 30\text{ V}$, $V_{BE(OFF)} = 0.5\text{ V}$, $I_C = 150\text{ mA}$, $I_{B1} = 15\text{ mA}$	t_d	-	10	ns
Rise Time at $V_{CC} = 30\text{ V}$, $V_{BE(OFF)} = 0.5\text{ V}$, $I_C = 150\text{ mA}$, $I_{B1} = 15\text{ mA}$	t_r	-	25	ns
Storage Time at $V_{CC} = 30\text{ V}$, $I_C = 150\text{ mA}$, $I_{B1} = -I_{B2} = 15\text{ mA}$	t_{stg}	-	225	ns
Fall Time at $V_{CC} = 30\text{ V}$, $I_C = 150\text{ mA}$, $I_{B1} = -I_{B2} = 15\text{ mA}$	t_f	-	60	ns

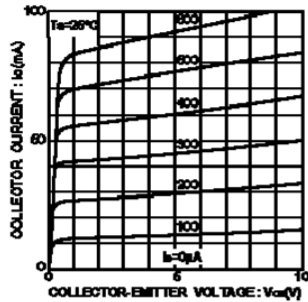


Fig.1 Grounded emitter output characteristics

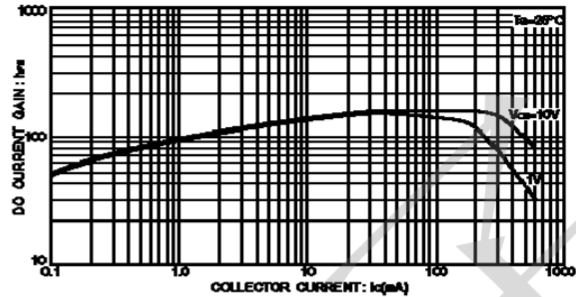


Fig.3 DC current gain vs. collector current (I)

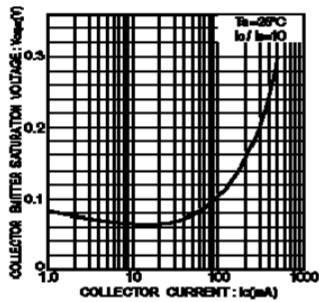


Fig.2 Collector-emitter saturation voltage vs. collector current

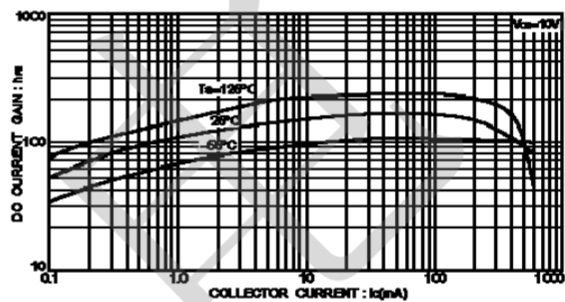


Fig.4 DC current gain vs. collector current (II)

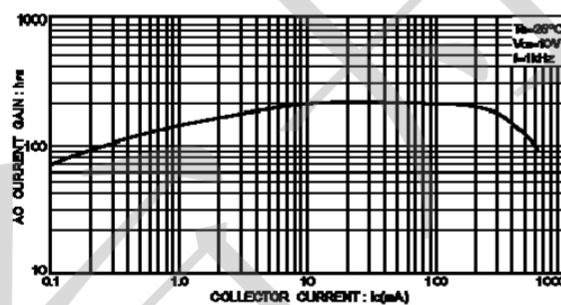


Fig.5 AC current gain vs. collector current

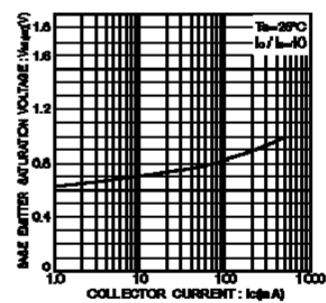
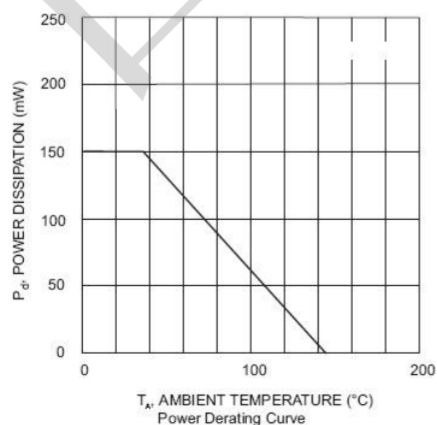


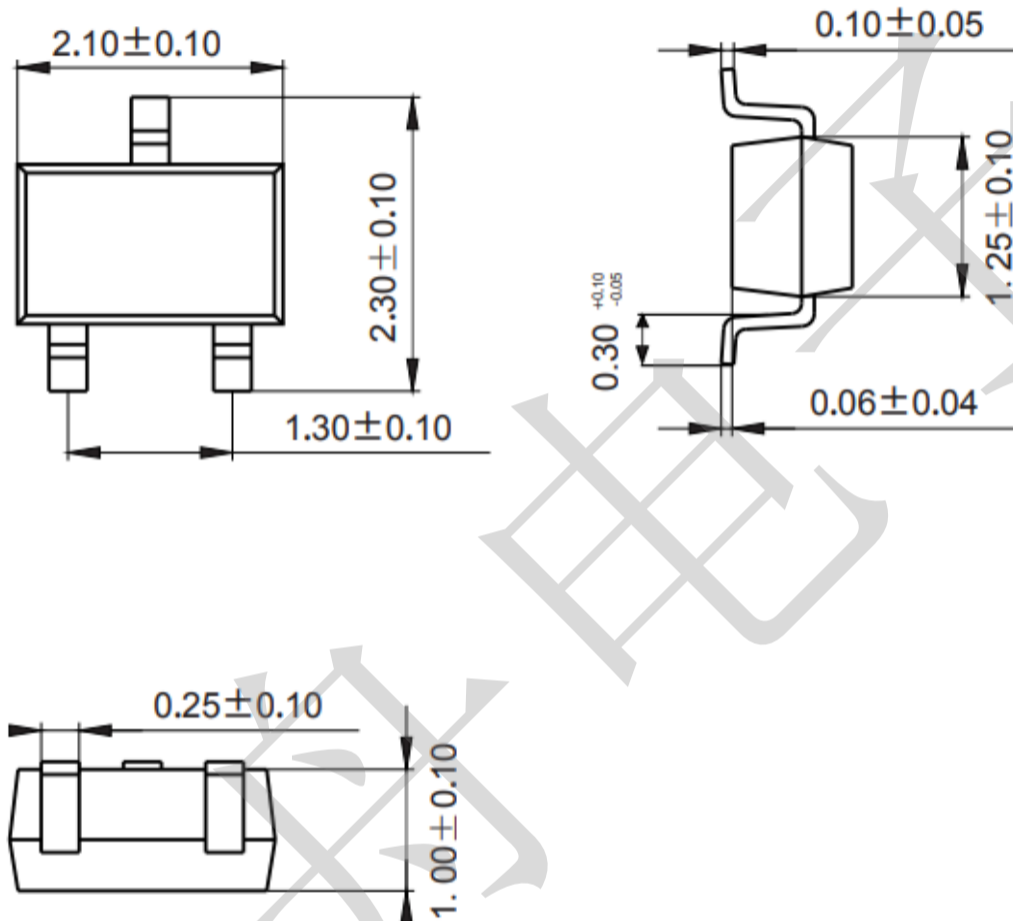
Fig.6 Base-emitter saturation voltage vs. collector current



T_A AMBIENT TEMPERATURE ($^{\circ}\text{C}$)
Power Derating Curve

Package Outline Dimensions (unit:mm)

SOT323



Mounting Pad Layout (unit: mm)

